NSN 5961-00-543-0376

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-543-0376 **Inclosure Material:** Metal **Overall Length:** 0.769 inches **Overall Diameter:** 0.635 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.780 inches **Thread Size:** 0.625 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 8.4 regulator voltage **Current Rating Per Characteristic:** 10.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius ambient air **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug **Specification Data:** 80131-release1554 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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